Research Article
An Efficient Metal-Free Hydrophilic Carbon as a Counter Electrode for Dye-Sensitized Solar Cells

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This study presents a new cost-effective metal-free counter electrode (CE) for dye-sensitized solar cells (DSSCs). CE was prepared by doctor blading a hydrophilic carbon (HC) particle on a fluorine-doped tin oxide substrate. Thereafter, HC CE was characterized using X-ray diffraction, profilometry, four-point probe testing, and cyclic voltammetry. A 2 μm thick HC CE revealed a comparable catalytic activity to that of the Pt electrode under the same experimental conditions. DSSC based on HC CE was analyzed and showed $J_{sc}$ of 6.87 mA/cm$^2$ close to that of DSSC with Pt CE (7.0 mA/cm$^2$). More importantly, DSSC based on HC CE yielded a power conversion efficiency ($\eta$) of 2.93% under AM 1.5 irradiation (100 mW/cm$^2$), which was comparable to that of DSSC based on standard Pt CE. These findings suggest that HC CE could be a promising CE for low-cost DSSCs.

1. Introduction

Silicon solar cell currently has the largest market share of 85% with conversion efficiency of approximately 25% [1]. However, this solar cell could not compete with conventional energy sources because of the high production cost that is mostly caused by the high purification process of the material. This issue motivated the scientist to find new methods to exploit the cheaper and highly efficient solar energy. Dye-sensitized solar cells (DSSCs), as third-generation solar cells, are the major variant in this approach [2, 3]. Since DSSC was invented by pioneers O’Regan and Grätzel in 1991 [4], this solar cell type has been introduced as one of the low-cost and highly efficient solar cells because of the availability of materials, low cost, and simple fabrication processes [5–9]. Over the last 10 years, the highest efficiency of DSSCs ever reported is approximately 12% [10, 11].

In principle, DSSCs comprise three main components, namely, photoanode, counter electrode (CE), and electrolyte (commonly iodide), as shown in Figure 1. The photoanode is an oxide semiconductor, such as TiO$_2$, deposited on a transparent conductive oxide (TCO) substrate. Thereafter, the TiO$_2$ surface is sensitized with dye (ruthenium complex), thereby contributing to the photon absorption and consequent electron injection. The electrolyte contains iodide-triiodide (I$^-$/I$_3^-$) redox couples transferring the electrons from the photoanode to the CE. The Pt deposited on the TCO substrate is commonly used as a standard CE because of its high conductivity and catalytic activity toward the redox couples in the electrolyte.

This type of DSSC with current material has a total production cost between $36 and $158/m$^2$ [12]. The major contribution (50%–60%) to the manufacturing cost of DSSCs arises from substrates, dyes, electrolytes, and Pt CEs. Therefore, the cost reduction improvement of DSSC is of immense interest [12]. Accordingly, researchers have been conducting studies to develop new sensitizers, photoanodes, redox couples, and CEs to fabricate cheap and efficient devices. Among these components, metal-free CEs are the best option to complement natural resources because Pt is expensive and rare. Pt corrosion in triiodide-containing solutions that generates platinum iodides, such as PtI$_4$, is also reported [13].

In this subject matter, carbon based CEs, such as graphite [14, 15], carbon black [16], graphene [17], activated carbon
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2.1 CE Preparation. The HC powder from Shion Co., Ltd. (Nagoya, Japan) was used to prepare HC CE. The HC paste was prepared by grinding 260 mg of HC powder with 0.4 mL of TiO$_2$ colloid, 0.8 mL of water, and 0.4 mL of 10% Triton X-100 (Fisher Chemical) aqueous solution. The TiO$_2$ colloid was prepared according to the procedures reported previously [24].

Prior to the deposition of CE on a fluorine-doped tin oxide (FTO) glass, FTOs with sheet resistance of approximately 8 Ω/sq (Pilkington) were cut into 1.5 cm × 2 cm. For the electrolyte inlet/outlet, two small holes were drilled in the middle of the substrate. The substrate was cleaned in an ultrasonic bath with acetone and isopropanol for 20 min in each step followed by drying under nitrogen flow.

Using the doctor blade technique, the paste was spread on the FTO substrate using a double Scotch tape and a glass rod followed by sintering in a cylinder furnace at 450°C for 30 min.

2.2 DSSC Preparation. Prior to the photoanode deposition, the FTO substrate with sheet resistance of 15 Ω/sq was cut, cleaned, and dried similar to the description for HC CE in Section 2.1. Thereafter, the 90°-T transparent titania paste (Dyesol Co.) was deposited on the conductive side of the FTO glass using the doctor blade technique [25, 26]. After deposition, the layer was annealed using a cylinder furnace set at 500°C in air for 30 min. The second layer of TiO$_2$-WER-40 (Dyesol Co.) was further deposited on top of the first layer as a scattering layer. The third layer was annealed similar to technique and temperature. TiCl$_4$ treatment was performed by dipping the freshly sintered TiO$_2$ films into an aqueous solution of 40 mM of TiCl$_4$ tetrahydrofuran (Sigma Aldrich) at 70°C for 30 min. The TiO$_2$ film was rinsed in deionized water and ethanol and dried under nitrogen flow.

After the TiCl$_4$ treatment, the TiO$_2$ film was sintered at 500°C for 30 min. The sintered electrode was maintained at 100°C for approximately 30 min before immersing into the dye solution. The TiO$_2$ film was then soaked for approximately 24 h at room temperature in a dye solution containing 0.3 mM of N719 (Solaronix) in acetonitrile and tert-butyl alcohol (1:1 volume ratio). After sensitization, the sensitized TiO$_2$ was rinsed with isopropanol and dried under nitrogen flow. To fabricate a DSSC, the photoanode and CE (Pt) with an active area of 1 cm$^2$ were encapsulated using a piece of hot melt film (Surlyn 1702; Solaronix) with a thickness of 25 μm and melted using hot press at 120°C for 20 s. A similar fabrication procedure was applied to assemble a photoanode with HC CE; the only difference was the sealant thickness, which was 90 μm. After sealing, two drops of iodine-based electrolyte were injected between the two electrodes through the predrilled holes on the FTO glass. Thereafter, the holes were sealed using the same sealant with a small glass slide to cover the hole and pressed for 10 s at 120°C. In this research, a liquid electrolyte based on iodine was prepared by dissolving 0.06 M of iodine (Sigma Aldrich) in 0.5 M of 4-tert-butyl pyridine (Sigma Aldrich) and 0.5 M of 1-butyl-3 methyl imidazolium iodide in acetonitrile solvent and 1-butyl-3 methyl imidazolium iodide (>98%; io.li.tec.).

3. Measurements

The HC CE crystal structure before and after the annealing treatment was identified through X-ray diffraction (XRD; Brucker) with Cu-Kα radiation (λ = 1.5418 Å). The thickness and surface morphologies, both in top and in cross-sectional views of a sintered HC CE, were identified using a field emission scanning electron microscope (FESEM; JEOL, JSM7000F). The HC CE atomic ratio was recorded using the energy dispersive X-ray spectroscopy (EDX) analysis. Surface profilometry (Brucker) was performed to determine the thickness and roughness of CEs. The sheet resistance of HC CE was measured using a four-point probe (Keithley, 2400 auto calculating) resistivity test system. Cyclic voltammetry
4. Results and Discussion

In CE, triiodide ions (I$_3^-$), which are produced by the reduction of oxidized sensitizer, are rereduced to I$^-$ ions. For this reaction to occur, a CE must have a high electrocatalytic activity [27]. A high crystalline structure is considerably preferable for achieving a high electrocatalytic activity, thereby reducing internal defects, decreasing electron-loss pathway, and subsequently increasing energy conversion efficiency [28]. XRD measurement was conducted in this study to identify the HC CE crystal structure before and after annealing treatment, as shown in Figure 2. The HC film has a good crystalline structure that contains graphite and mellitic acid (benzene hexacarboxylic acid: C$_{12}$H$_6$O$_{12}$) with hexagonal and orthorhombic phase shapes, respectively. Further, the amorphous structures of TiO$_2$ could be observed with monoclinic phase shape. The peak of (002) at 2$\theta$ = 26.4° contributed to the graphite, whereas other peaks well fitted with those of cassiterite (referring to FTO). No changes were observed in the position of the graphite peaks after annealing. However, the crystallinity of graphite intensified from 215 counts to 663 counts after annealing.

Figure 3 displays the top and cross-sectional views of the FESEM images of the HC film on a FTO substrate along with its atomic ratio. The inset (Figure 3(a)) shows the high-magnification image of the film. The HC film uniformly covered the substrate surface, thereby resulting in a crack-free HC film. A highly porous structure of the film with spherical HC particle was also observed. The cross-sectional view (Figure 3(b)) indicates thicknesses of 2.15 and 1$\mu$m for the HC film and FTO covered glass substrate, respectively.

The atomic ratio of the HC film was estimated through EDX analysis (Figure 3(c)). The result showed that HC CE mostly contained carbon (~80%) with 4% titanium and 16% oxygen. Annealing treatment of the HC film was also performed under nitrogen flow to reduce the oxygen ratio in the film. However, this approach caused the carbon layer to fall off from the FTO substrate. It can be suggested that the oxygen functional groups in the HC film improved the adhesion between the FTO substrate and the HC layer, as well as among the HC particles.

Carbonaceous materials with rough surface provide considerable reduction sites or the surface area for CE to react with electrolytes, thereby resulting in the electrode's high catalytic activity [29]. Film thickness is also an important factor in determining the CE properties because it affects both the conductivity and catalytic activity of the electrode [30, 31]. Profilometry measurement was conducted to identify the surface roughness and thickness of HC CE. The results showed average roughness and thickness of 0.9 and 2.09$\mu$m, respectively, for HC CE, whereas they were 180 and 240 nm, respectively, for the Pt electrode prepared under the same condition. The layer thickness identified by the profilometry measurement was nearly in agreement with the FESEM results showing a thickness of 2.15$\mu$m for the HC film.

Electrical conductivity and catalytic activity are two major factors that significantly affect the CE performance in DSSCs. Therefore, large conductivity and catalytic activity could result in higher energy conversion efficiency. The sheet resistance of HC CE was recorded using the four-point probe technique. The sheet resistivity of HC CE was determined to
Figure 3: (a) Top view and (b) cross-sectional view of FESEM image for the HC film on FTO covered glass substrate. (c) Weight and atomic ratio of HC film estimated by EDX analysis.

<table>
<thead>
<tr>
<th>Element</th>
<th>Line type</th>
<th>Apparent concentration</th>
<th>Wt%</th>
<th>Wt%</th>
<th>Atomic%</th>
</tr>
</thead>
<tbody>
<tr>
<td>C</td>
<td>K series</td>
<td>7.57</td>
<td>67.47</td>
<td>0.37</td>
<td>79.46</td>
</tr>
<tr>
<td>O</td>
<td>K series</td>
<td>2.13</td>
<td>18.57</td>
<td>0.30</td>
<td>16.42</td>
</tr>
<tr>
<td>Ti</td>
<td>K series</td>
<td>1.43</td>
<td>13.96</td>
<td>0.33</td>
<td>4.12</td>
</tr>
<tr>
<td>Total:</td>
<td></td>
<td></td>
<td>100.00</td>
<td>100.00</td>
<td></td>
</tr>
</tbody>
</table>

Figure 4: Cyclic voltammograms of Pt and HC film obtained at a scan rate of 50 mV/s. In the CV curves, two pairs of oxidation and reduction peaks (Ox-1/Red-1 and Ox-2/Red-2, respectively, as labeled in Figure 4) were resolved well in the range from −1 V to 1 V. The left and right pairs are assigned to (1) and (2), respectively. Consider the following:

\[
\begin{align*}
I_3^- + 2e^- & \rightarrow 3I^- \\
3I_2^- + 2e^- & \rightarrow 2I_3^- 
\end{align*}
\]

The peaks obtained at the positive side are known as anodic peaks, which refer to the oxidation of iodide and triiodide. The peaks obtained at the negative section are the cathodic peaks, which correspond to the reduction of triiodide [32]. Consequently, the overall feature of CV for the HC electrode was similar to that for the Pt electrode, whereas HC CE represented a slightly faster oxidation rate (Ox-1 and Ox-2). In detail, HC CE exhibited Ox-1 and Ox-2 of 0.70 mA/cm² and 0.45 mA/cm², respectively, whereas they were 0.68 mA/cm² and 0.40 mA/cm², respectively, for the Pt electrode. HC CE revealed a lower reduction current density (Red-1) than that of the Pt electrode (0.75 mA/cm²), thereby contributing to a lower catalytic activity of HC CE because of the few catalytic sites for triiodide reduction. Nevertheless, a comparable catalytic activity to the Pt electrode was observed for HC CE, which could be attributed to the electrode’s porous structure and large surface area, mainly favored by the addition of TiO₂ colloid to the HC particle, as reported earlier [24].
Table 1: Photovoltaic parameters of the cells shown in Figure 6. The errors are the SD values calculated from three measurements of three different devices for each film.

<table>
<thead>
<tr>
<th>CE</th>
<th>$R_s$ (Ω)</th>
<th>$J_{sc}$ (mA/cm$^2$)</th>
<th>$V_{oc}$ (V)</th>
<th>FF%</th>
<th>$\eta$%</th>
</tr>
</thead>
<tbody>
<tr>
<td>Pt</td>
<td>41.02 ± 1.20</td>
<td>7.0 ± 0.1</td>
<td>0.75 ± 0.00</td>
<td>68.71 ± 0.12</td>
<td>3.57 ± 0.06</td>
</tr>
<tr>
<td>HC</td>
<td>43.94 ± 0.78</td>
<td>6.87 ± 0.11</td>
<td>0.74 ± 0.00</td>
<td>57.26 ± 0.62</td>
<td>2.93 ± 0.06</td>
</tr>
</tbody>
</table>

Figure 5: 50 successive cycles of HC CE obtained at a scan rate of 50 mV/s.

Figure 6: Comparison of $I$-$V$ characteristics of DSSCs fabricated with Pt and HC CE under 1 sun illumination (AM 1.5, 100 mW/cm$^2$).

A total of 50 consecutive CV scans were performed to investigate the stability of HC CE. Figure 5 shows the result. The shapes of the curves presented no evident change in the consecutive scans, thereby exhibiting stable anodic and cathodic peak currents. Thus, HC CE had reasonable chemical stability and was firmly deposited on the FTO substrate.

Three complete DSSC devices based on each HC and Pt CE were tested to study the performance of DSSC using the $I$-$V$ measurement. Thereafter, the average value and standard deviation among different devices were calculated. Figure 6 shows the $I$-$V$ curves of DSSC using HC and Pt CEs. The measurement was conducted under an AM 1.5 solar simulator at 100 mW/cm$^2$ intensity.

Table 1 presents a summary of the detailed photovoltaic parameters of HC and Pt CEs, including short current density ($J_{sc}$), open-circuit voltage ($V_{oc}$), fill factor (FF), cell efficiency ($\eta$), and series resistance ($R_s$). Note that DSSC using HC CE had $J_{sc}$ of 6.87 mA/cm$^2$, which approximated that of DSSC with a Pt CE of 7.0 mA/cm$^2$. Comparable $J_{sc}$ was favored by the high surface roughness of HC CE, thereby resulting in a comparable efficiency of 2.93% to the Pt-based DSSC with efficiency of 3.57%.

The lower cell efficiency using HC CE was mainly caused by its lower FF than that of the Pt-based cells. The lower FF was probably caused by the higher series resistance of HC CE (41.02 Ω) than that of the Pt-based cell, which may be attributed to the significantly larger thickness of HC CE. Although a high thickness substantially increased the surface area for triiodide reduction, such characteristic also increased the average electron transport length before reaching the site for triiodide reduction, as well as the internal series resistance [33].

Nevertheless, HC CE has its own advantages of having a large surface area and high porosity that could compensate the effects of the higher series resistance, thereby resulting in comparable efficiency to that of the Pt-based cell.

Moreover, no apparent difference in $V_{oc}$ of Pt- and HC-based DSSCs was observed. It should be also noted that these results were not high compared with the results reported in previous studies. The objective of the current research was not to obtain an optimized device but to conduct a comparative study on alternative CE to replace Pt.

5. Conclusion

This study investigated a new type of CE for triiodide reduction in DSSCs. CE was prepared using HC particle and successfully deposited on an FTO glass substrate using the doctor blade technique. The results indicated HC CE’s high surface roughness and good conductivity and catalytic activity. Furthermore, DSSC with HC CE exhibited a comparable photovoltaic performance with an efficiency of 2.93% to DSSCs with Pt CE (3.57%). The low photovoltaic performance was due to the high series resistance of the HC-based DSSC. Although the high-cost Pt CE still appears the best among the tested CEs and exhibited the best performance, the HC particle has the potential to be employed as a CE for DSSC and can be expected to lead to a low-cost and stable DSSC.

Future studies can focus on advanced coating methods, such as screen printing, to attain stable and uniform coating for the considerably low resistivity of HC CE. Other conductive materials, such as polymers, nanocarbon, and CNT, may also be incorporated into the fabrication methods of HC CE to
increase the electrode’s conductivity and catalytic activity, thereby making it highly comparable to Pt CE.

**Competing Interests**

The authors declare that there are no competing interests regarding the publication of this paper.

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